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### Dual 60V P-Channel PowerTrench<sup>®</sup> MOSFET

### **General Description**

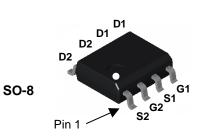
This P-Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gate drive voltage ratings (4.5V - 20V).

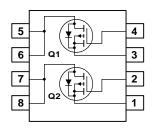
### Applications

- Power management
- Load switch
- Battery protection

### Features

- $\label{eq:relation} \bullet \ -2.3 \ A, \ -60 \ V \qquad R_{\text{DS}(\text{ON})} = 250 \ m\Omega \ @ \ V_{\text{GS}} = -10 \ V \\ R_{\text{DS}(\text{ON})} = 500 \ m\Omega \ @ \ V_{\text{GS}} = -4.5 \ V \\ \end{array}$
- Low gate charge (9nC typical)
- Fast switching speed
- High performance trench technology for extremely
  low R<sub>DS(ON)</sub>
- High power and current handling capability





### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol		Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain-Source	e Voltage			-60	V
V <sub>GSS</sub>	Gate-Sourc	e Voltage			±20	V
I <sub>D</sub>	Drain Curre	nt – Continuous	1)	Note 1a)	-2.3	A
		– Pulsed			-10	
PD	Power Diss	Power Dissipation for Dual Operation			2	W
	Power Diss	ipation for Single Operat	tion (f	Note 1a)	1.6	
			1)	Note 1b)	1.0	
			(1	Note 1c)	0.9	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range			-55 to +175	°C	
Therma	I Charac	teristics				
$R_{\theta JA}$	Thermal Re	sistance, Junction-to-Ar	nbient (r	Note 1a)	78	°C/W
			(N	lote 1c)	135	°C/W
$R_{\theta JC}$	Thermal Re	Resistance, Junction-to-Case (Note 1)		lote 1)	40	
Packag	e Markin	g and Ordering	Inform	ation		
•	Marking	Device	Reel S		Tape width	Quantity
NDS	9948	NDS9948	13"		12mm	2500 units

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# NDS9948

January 2010

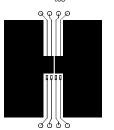
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	burce Avalanche Ratings (Note	e 2)				
W <sub>DSS</sub>	Drain-Source Avalanche Energy	Single Pulse, V <sub>DD</sub> =-54 V			15	mJ
I <sub>AR</sub>	Drain-Source Avalanche Current				-10	A
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \qquad I_D = -250 \mu\text{A}$	-60			V
ΔBV <sub>DSS</sub> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		-52		mV/°0
I <sub>DSS</sub>	Zero Gate Voltage Drain Current				-2 -25	μA
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
	Gate-Body Leakage, Reverse	$V_{GS} = -20 \text{ V} \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	-1	-1.5	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		4		mV/°0
-	Static Drain–Source	$V_{GS} = -10 \text{ V}, \qquad I_D = -2.3 \text{ A}$		138	250	mΩ
	On–Resistance	$V_{GS} = -4.5 \text{ V},  I_D = -1.6 \text{ A}$		175	500	
1	On–State Drain Current	$V_{GS} = -10 V, I_D = -2.3A, T_J = 125^{\circ}C$ $V_{GS} = -10 V, V_{DS} = -5 V$	-10	225	433	٨
D(on)	Forward Transconductance	$V_{GS} = -10 \text{ V},  V_{DS} = -5 \text{ V}$ $V_{DS} = -10 \text{ V},  I_D = -2.3 \text{ A}$	-10	5		A S
g <sub>FS</sub>		VDS - 10 V, 10 - 2.0 A		5		0
	c Characteristics		1	204		
Ciss	Input Capacitance	$V_{DS} = -30 \text{ V},  V_{GS} = 0 \text{ V},$		394		pF
	Output Capacitance	f = 1.0 MHz		53 23		pF pF
Crss	Reverse Transfer Capacitance			23		рг
	ng Characteristics (Note 2)	1	<u> </u>			<u> </u>
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = -30 \text{ V},  I_D = -1 \text{ A},$ $V_{GS} = -10 \text{ V},  R_{GEN} = 6 \Omega$		6	12	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{GS} = -10$ V, $R_{GEN} = 6 \Omega$		9	18	ns
t <sub>d(off)</sub>	Turn–Off Delay Time	_		16	29	ns
t <sub>f</sub>	Turn–Off Fall Time			3	6	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -30 \text{ V}, \qquad I_D = -2.3 \text{ A},$ $V_{GS} = -10 \text{ V}$		9	13	nC
Q <sub>gs</sub>	Gate-Source Charge	-		1.4		nC
Q <sub>gd</sub>	Gate–Drain Charge			1.7		nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-S	ource Diode Characteristics	s and Maximum Ratings		•		
ls	Maximum Continuous Drain-Source	ce Diode Forward Current			-1.7	А
$V_{SD}$	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = -1.7 A(Note 2)$		-0.8	-1.2	V
t <sub>rr</sub>	Reverse Recovery Time	$V_{GS} = 0 V$ , $I_F = -2.3A$ , $dI_F/dt = 100A/\mu s$		25		nS

Notes:

1. R<sub>8JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>8JC</sub> is guaranteed by design while R<sub>8CA</sub> is determined by the user's board design.

b)





a)



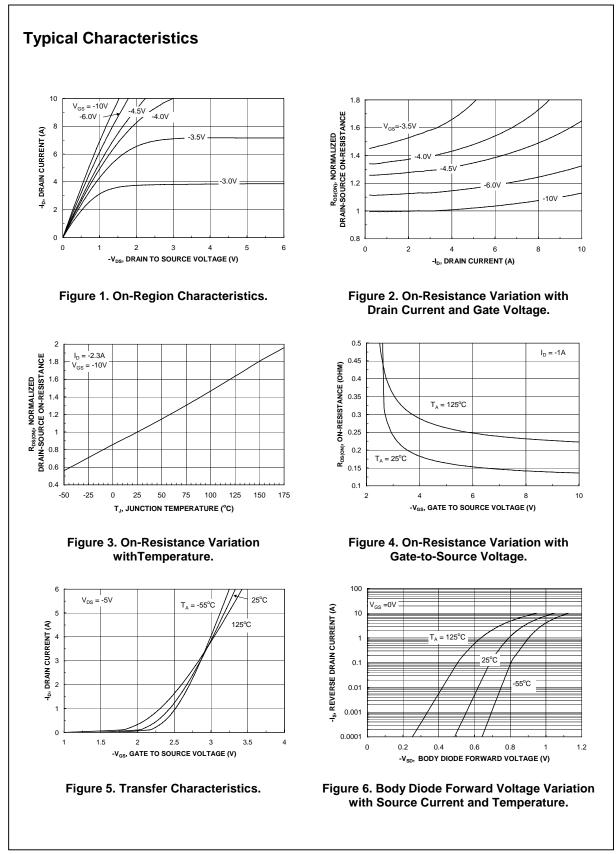
125°C/W when mounted on a 0.02 in<sup>2</sup> pad of 2 oz copper

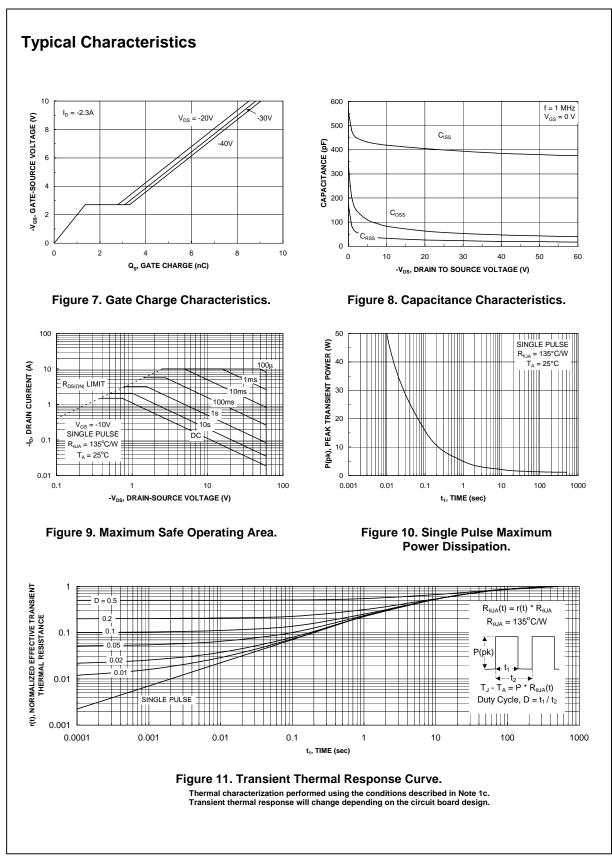
c)

135°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%





NDS9948 Rev B1(W)



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